74AUP1G57

Low-power configurable multiple function gateRev. 7 — 16 September 2015

Product data sheet

General description 1.

The 74AUP1G57 provides configurable multiple functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions AND, OR, NAND, NOR, XNOR, inverter, and buffer. All inputs can be connected to $\ensuremath{V_{\text{CC}}}$ or GND.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74AUP1G57 has Schmitt trigger inputs making it capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_H.

Features and benefits 2.

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



Low-power configurable multiple function gate

3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1G57GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363				
74AUP1G57GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886				
74AUP1G57GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891				
74AUP1G57GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74AUP1G57GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 \times 1.0 \times 0.35 mm	SOT1202				
74AUP1G57GX	–40 °C to +125 °C	X2SON6	plastic thermal extremely thin small outline package; no leads; 6 terminals; body 1 \times 0.8 \times 0.35 mm	SOT1255				

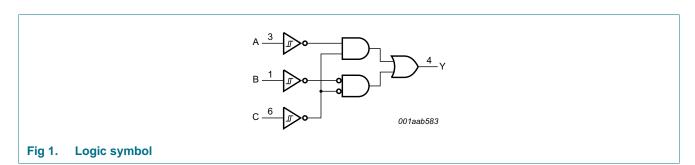
4. Marking

Table 2. Marking

Type number	Marking code ^[1]
74AUP1G57GW	аС
74AUP1G57GM	аС
74AUP1G57GF	аС
74AUP1G57GN	аС
74AUP1G57GS	aC
74AUP1G57GX	aC

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

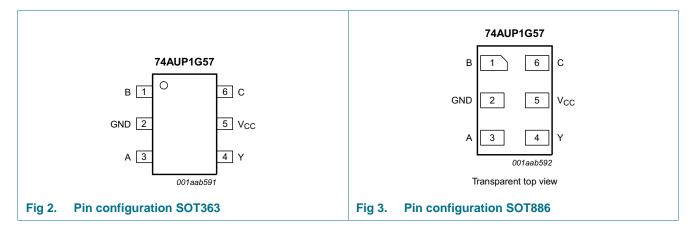
5. Functional diagram



Low-power configurable multiple function gate

6. Pinning information

6.1 Pinning





6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
A	3	data input
Υ	4	data output
V _{CC}	5	supply voltage
С	6	data input

Low-power configurable multiple function gate

7. Functional description

Table 4. Function table[1]

Input	Output		
С	В	A	Υ
L	L	L	Н
L	L	Н	L
L	Н	L	Н
L	Н	Н	L
Н	L	L	L
Н	L	Н	L
Н	Н	L	Н
Н	Н	Н	Н

^[1] H = HIGH voltage level; L = LOW voltage level.

7.1 Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input AND	see Figure 6
2-input AND with both inputs inverted	see Figure 9
2-input NAND with inverted input	see Figure 7 and Figure 8
2-input OR with inverted input	see Figure 7 and Figure 8
2-input NOR	see Figure 9
2-input NOR with both inputs inverted	see Figure 6
2-input XNOR	see Figure 10
Inverter	see Figure 11
Buffer	see Figure 12

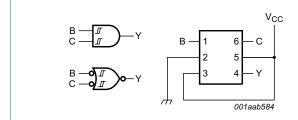


Fig 6. 2-input AND gate or 2-input NOR gate with both inputs inverted

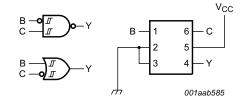


Fig 7. 2-input NAND gate with input B inverted or 2-input OR gate with inverted C input

Low-power configurable multiple function gate

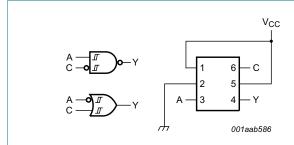


Fig 8. 2-input NAND gate with input C inverted or 2-input OR gate with inverted A input

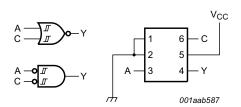
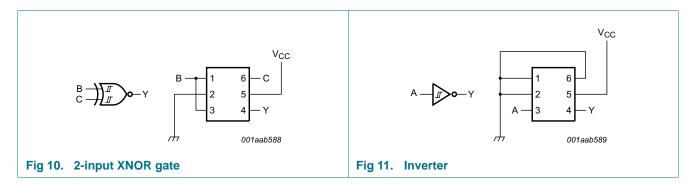
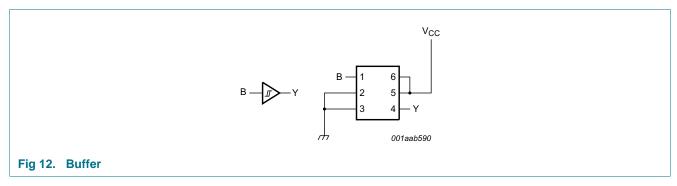


Fig 9. 2-input NOR gate or 2-input AND gate with both inputs inverted





8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±20	mA
I _{CC}	supply current			-	50	mA

Low-power configurable multiple function gate

 Table 6.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$	-	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C	$ \begin{array}{c} \text{Ige} & \begin{array}{c} V_{I} = V_{T+} \text{ or } V_{T-} \\ I_{O} = -20 \ \mu \text{A}; \ V_{CC} = 0.8 \ V \text{ to } 3.6 \ V \\ \hline I_{O} = -1.1 \ \text{mA}; \ V_{CC} = 1.1 \ V \\ \hline I_{O} = -1.7 \ \text{mA}; \ V_{CC} = 1.4 \ V \\ \hline I_{O} = -1.9 \ \text{mA}; \ V_{CC} = 1.65 \ V \\ \hline I_{O} = -2.3 \ \text{mA}; \ V_{CC} = 1.65 \ V \\ \hline I_{O} = -2.3 \ \text{mA}; \ V_{CC} = 2.3 \ V \\ \hline I_{O} = -3.1 \ \text{mA}; \ V_{CC} = 2.3 \ V \\ \hline I_{O} = -2.7 \ \text{mA}; \ V_{CC} = 2.3 \ V \\ \hline I_{O} = -2.7 \ \text{mA}; \ V_{CC} = 3.0 \ V \\ \hline I_{O} = -4.0 \ \text{mA}; \ V_{CC} = 3.0 \ V \\ \hline I_{O} = 20 \ \mu \text{A}; \ V_{CC} = 0.8 \ V \text{ to } 3.6 \ V \\ \hline I_{O} = 1.1 \ \text{mA}; \ V_{CC} = 1.4 \ V \\ \hline I_{O} = 1.7 \ \text{mA}; \ V_{CC} = 1.4 \ V \\ \hline I_{O} = 1.9 \ \text{mA}; \ V_{CC} = 1.65 \ V \\ \hline I_{O} = 1.9 \ \text{mA}; \ V_{CC} = 1.65 \ V \\ \hline I_{O} = 2.3 \ \text{mA}; \ V_{CC} = 2.3 \ V \\ \hline I_{O} = 3.1 \ \text{mA}; \ V_{CC} = 2.3 \ V \\ \hline \end{array}$				
V _{OH} HIGH-level output	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_O = -20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V _{CC} - 0.1	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.32	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_O = 20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		$I_O = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	-	-	$0.3 \times V_{CC}$	V
		$I_O = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.31	V
		$I_O = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.31	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		$I_O = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.44	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$			0.31	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V

74AUP1G57

All information provided in this document is subject to legal disclaimers.

^[2] For SC-88 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.
For X2SON6 and XSON6 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

Low-power configurable multiple function gate

 Table 8.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Iį	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
ΔI_{OFF}	additional power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	_{CC} = 0 V to 0.2 V		±0.2	μА
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μΑ
Δl _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	-	-	40	μΑ
Cı	input capacitance	$V_I = GND \text{ or } V_{CC}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	1.1	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$		1.7	-	pF
T _{amb} = -4	40 °C to +85 °C					
	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_{O} = -20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V _{CC} - 0.1	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
		$I_O = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
I _I	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μΑ
I_{OFF}	power-off leakage current	V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μΑ
ΔI_{OFF}	additional power-off leakage current	$V_1 \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$			±0.6	μΑ
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$			0.9	μΑ
Δl _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	-	-	50	μΑ

Low-power configurable multiple function gate

 Table 8.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
-	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_{O} = -20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V _{CC} - 0.11	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.6 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	0.93	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.17	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
V _{OL} LOW-level output voltage		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_{O} = 20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.33 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.36	V
		$I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.50	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.50	V
I _I	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
ΔI_{OFF}	additional power-off leakage current	$V_I \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$			±0.75	μΑ
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$			1.4	μΑ
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	-	-	75	μΑ

Low-power configurable multiple function gate

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 14.

Symbol	Parameter	Conditions		25 °C			-4	Unit		
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 p	F									
t _{pd}	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V _{CC} = 0.8 V		-	22.6	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		2.8	6.5	12.6	2.5	13.0	13.2	ns
		V _{CC} = 1.4 V to 1.6 V		2.2	4.6	7.6	2.5	8.2	8.6	ns
		V _{CC} = 1.65 V to 1.95 V		2.1	3.9	6.2	2.0	6.8	7.2	ns
		V _{CC} = 2.3 V to 2.7 V		2.0	3.1	4.5	1.8	5.1	5.3	ns
		V _{CC} = 3.0 V to 3.6 V		1.8	2.8	3.9	1.5	4.1	4.3	ns
C _L = 10	pF									-
t _{pd}	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V _{CC} = 0.8 V		-	26.1	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.2	7.3	14.4	2.8	14.9	15.2	ns
		V _{CC} = 1.4 V to 1.6 V		2.6	5.2	8.7	2.8	9.3	9.8	ns
		V _{CC} = 1.65 V to 1.95 V		2.5	4.5	7.0	2.2	7.8	8.2	ns
		V _{CC} = 2.3 V to 2.7 V		2.4	3.7	5.2	2.1	5.9	6.2	ns
		V _{CC} = 3.0 V to 3.6 V		2.3	3.4	4.6	1.9	4.9	5.1	ns
C _L = 15	pF									
t _{pd}	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V _{CC} = 0.8 V		-	31.6	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.4	8.0	15.7	3.1	16.7	17.0	ns
		V _{CC} = 1.4 V to 1.6 V		2.8	5.7	9.4	3.1	10.4	10.9	ns
		V _{CC} = 1.65 V to 1.95 V		2.6	4.9	7.7	2.5	8.7	9.2	ns
		V _{CC} = 2.3 V to 2.7 V		2.6	4.1	5.7	2.4	6.5	6.9	ns
		V _{CC} = 3.0 V to 3.6 V		2.5	3.8	5.0	2.2	5.5	5.7	ns

Low-power configurable multiple function gate

 Table 9.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 14.

Symbol	Parameter	Conditions		25 °C			-40 °C to +125 °C			Unit
			Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)		
C _L = 30 p	oF.									
t _{pd}	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V _{CC} = 0.8 V		-	37.8	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		4.6	10.4	20.9	3.9	21.8	22.3	ns
		V _{CC} = 1.4 V to 1.6 V		3.6	7.4	12.2	3.8	13.4	14.1	ns
		V _{CC} = 1.65 V to 1.95 V		3.5	6.2	9.9	3.1	11.1	11.8	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		3.4	5.2	7.4	3.1	8.3	8.8	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		3.2	4.9	6.6	2.8	7.0	7.4	ns
C _L = 5 pl	F, 10 pF, 15 pF and	30 pF								
C_{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$	[3][4]							
		$V_{CC} = 0.8 \text{ V}$		-	2.6	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V		-	2.8	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V		-	2.9	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V		-	3.1	-	-	-	-	pF
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-	3.7	-	-	-	-	pF
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		-	4.3	-	-	-	-	pF

- [1] All typical values are measured at nominal V_{CC} .
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] All specified values are the average typical values over all stated loads.
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

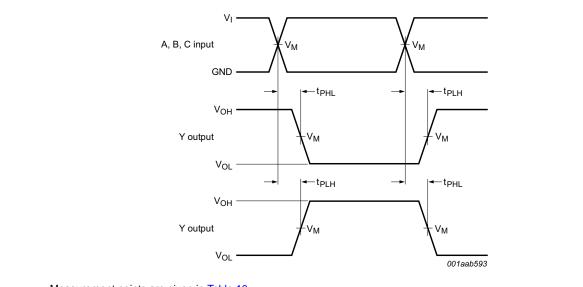
 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of the outputs.

Low-power configurable multiple function gate

12. Waveforms



Measurement points are given in Table 10.

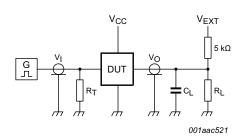
 V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig 13. Input A, B and C to output Y propagation delay times

Table 10. Measurement points

Supply voltage	Output	Input				
V _{CC}	V _M	V _M	VI	$t_r = t_f$		
0.8 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns		

Low-power configurable multiple function gate



Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 14. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load	V _{EXT}			
V _{CC}	C _L	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times, R_L = 5 k Ω . For measuring propagation delays, set-up and hold times, and pulse width, R_L = 1 M Ω .

Low-power configurable multiple function gate

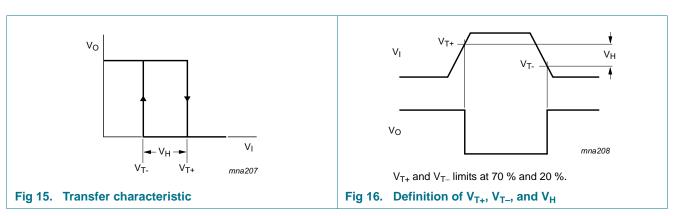
13. Transfer characteristics

Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 14</u>.

Symbol	Parameter	Conditions		25 °C			-40 °C to +125 °C			Unit
				Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V_{T+}	positive-going threshold voltage	see Figure 15 and Figure 16								
		V _{CC} = 0.8 V	(0.30	-	0.60	0.30	0.60	0.62	V
		V _{CC} = 1.1 V	(0.53	-	0.90	0.53	0.90	0.92	V
		V _{CC} = 1.4 V	(0.74	-	1.11	0.74	1.11	1.13	V
		V _{CC} = 1.65 V	(0.91	-	1.29	0.91	1.29	1.31	V
		V _{CC} = 2.3 V		1.37	-	1.77	1.37	1.77	1.80	V
		V _{CC} = 3.0 V		1.88	-	2.29	1.88	2.29	2.32	V
V _T	negative-going threshold voltage	see Figure 15 and Figure 16								
		V _{CC} = 0.8 V	(0.10	-	0.60	0.10	0.60	0.60	V
		V _{CC} = 1.1 V	(0.26	-	0.65	0.26	0.65	0.65	V
		V _{CC} = 1.4 V	(0.39	-	0.75	0.39	0.75	0.75	V
		V _{CC} = 1.65 V	(0.47	-	0.84	0.47	0.84	0.84	V
		V _{CC} = 2.3 V	(0.69	-	1.04	0.69	1.04	1.04	V
		V _{CC} = 3.0 V	(0.88	-	1.24	0.88	1.24	1.24	V
V _H	hysteresis voltage	(V _{T+} – V _{T-}); see <u>Figure 15</u> , <u>Figure 16</u> , <u>Figure 17</u> and <u>Figure 18</u>								
		V _{CC} = 0.8 V	(0.07	-	0.50	0.07	0.50	0.50	V
		V _{CC} = 1.1 V	(0.08	-	0.46	0.08	0.46	0.46	V
		V _{CC} = 1.4 V	(0.18	-	0.56	0.18	0.56	0.56	V
		V _{CC} = 1.65 V	(0.27	-	0.66	0.27	0.66	0.66	V
		V _{CC} = 2.3 V	(0.53	-	0.92	0.53	0.92	0.92	V
		V _{CC} = 3.0 V	(0.79	-	1.31	0.79	1.31	1.31	V

14. Waveform transfer characteristics



74AUP1G57

All information provided in this document is subject to legal disclaimers.

© Nexperia B.V. 2017. All rights reserved

Low-power configurable multiple function gate

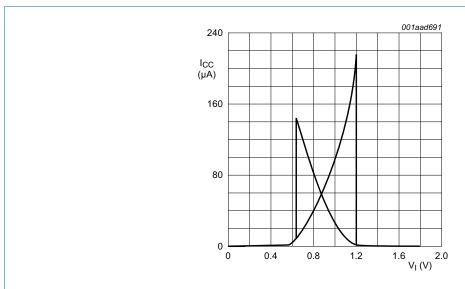


Fig 17. Typical transfer characteristics; $V_{CC} = 1.8 \text{ V}$

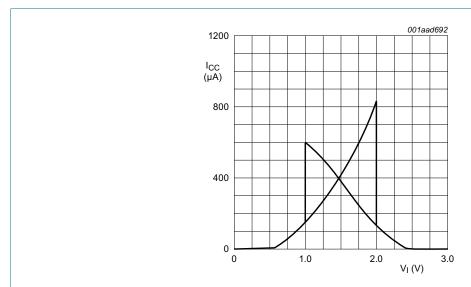


Fig 18. Typical transfer characteristics; $V_{CC} = 3.0 \text{ V}$

74AUP1G57

15. Package outline

SOT363 Plastic surface-mounted package; 6 leads Α X = v (M) A ΗE ⊕ w M B е detail X scale **DIMENSIONS (mm are the original dimensions)** Α1 UNIT D Q Α С Ε ٧ e₁ H_{E} $L_{\mathbf{p}}$ w у max 0.25 0.30 0.25 0.10 1.35 1.15 2.2 2.0 0.45 1.1 2.2 0.1 0.8 0.20 1.8 0.15 0.15 REFERENCES EUROPEAN OUTLINE ISSUE DATE VERSION JEDEC **PROJECTION** IEC JEITA 04-11-08 SOT363 SC-88 \bigcirc 06-03-16

Fig 19. Package outline SOT363 (SC-88)

74AUP1G57

All information provided in this document is subject to legal disclaimers.

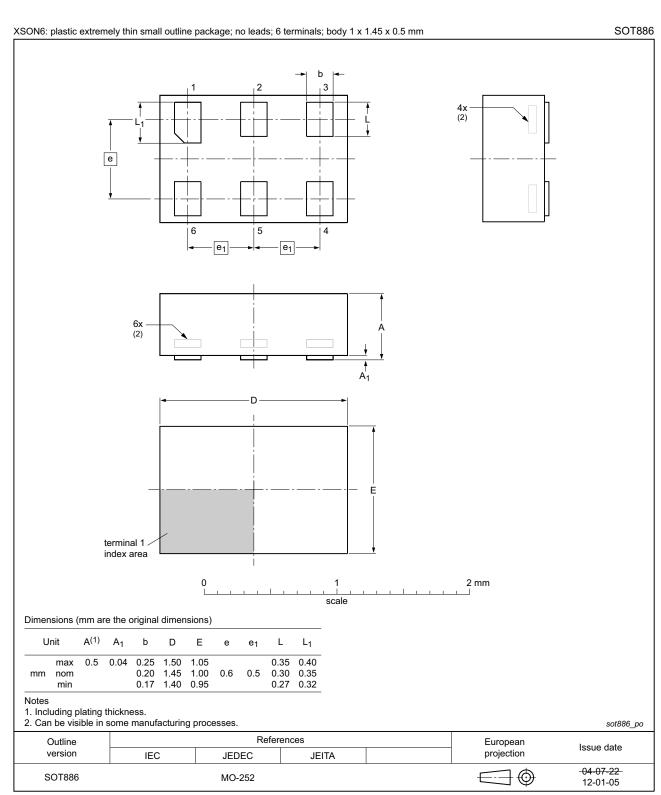


Fig 20. Package outline SOT886 (XSON6)

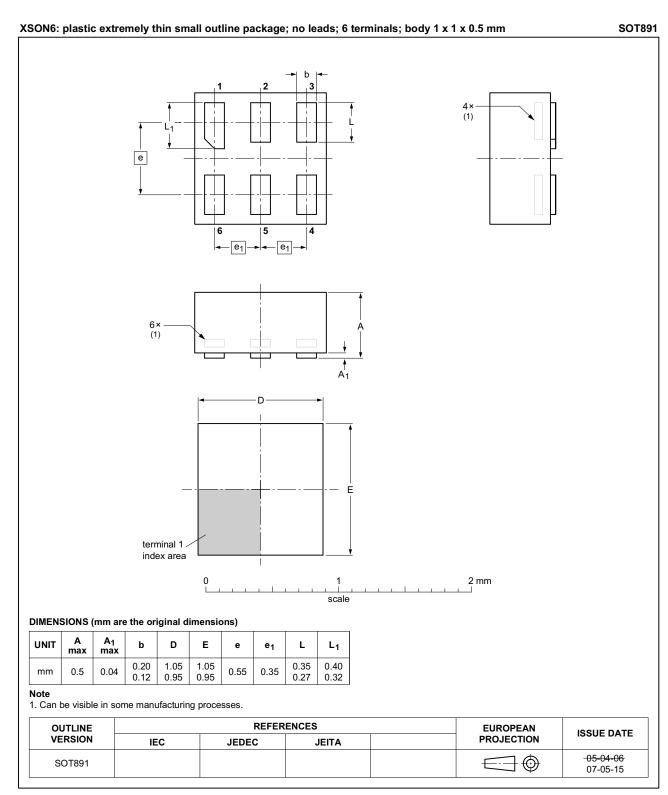


Fig 21. Package outline SOT891 (XSON6)

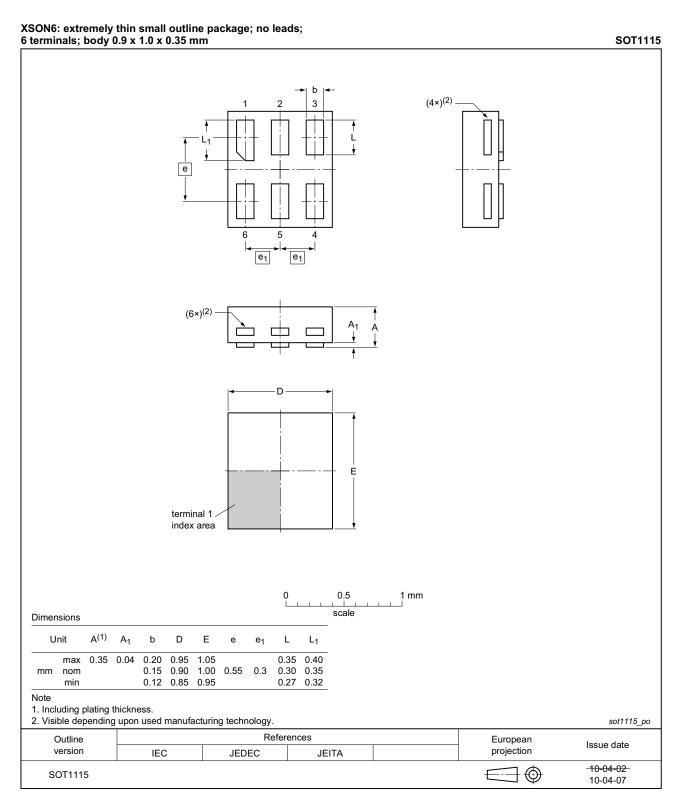


Fig 22. Package outline SOT1115 (XSON6)

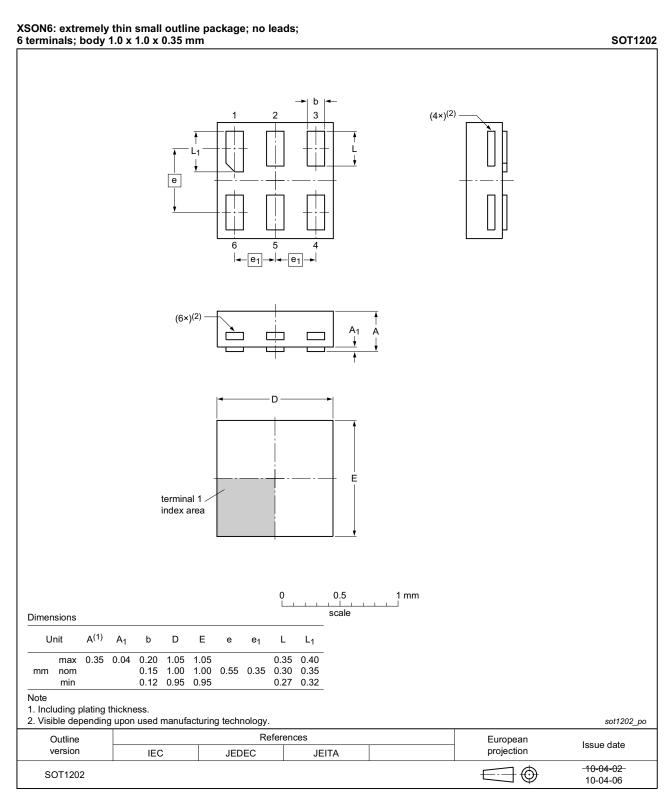


Fig 23. Package outline SOT1202 (XSON6)

74AUP1G57

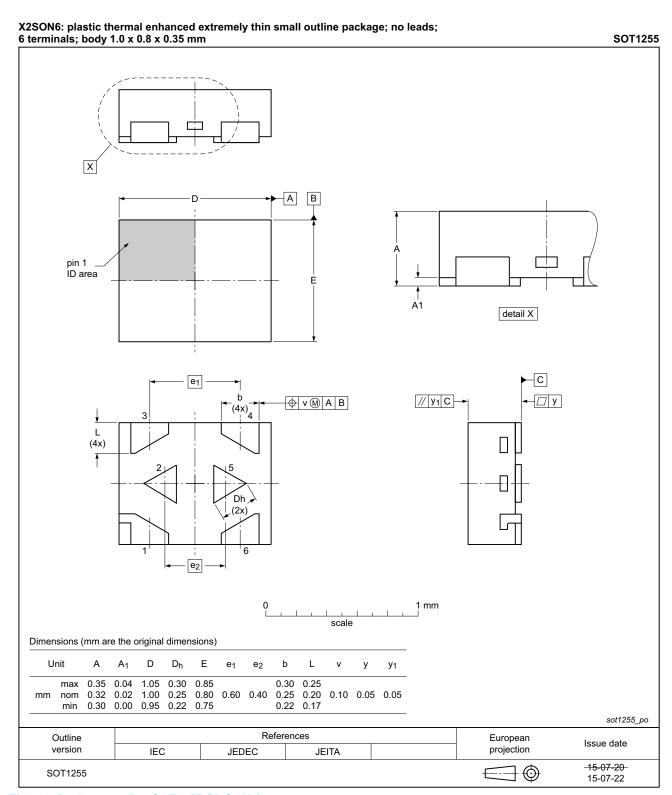


Fig 24. Package outline SOT1255 (X2SON6)

Low-power configurable multiple function gate

16. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

17. Revision history

Table 14. Revision history

Release date	Data sheet status	Change notice	Supersedes
20150916	Product data sheet	-	74AUP1G57 v.6
Added type no	umber 74AUP1G57GX (SOT1	255/X2SON6).	
20120815	Product data sheet	-	74AUP1G57 v.5
Package outling	ne drawing of SOT886 (Figure	20) modified.	
20111125	Product data sheet	-	74AUP1G57 v.4
20100720	Product data sheet	-	74AUP1G57 v.3
20090622	Product data sheet	-	74AUP1G57 v.2
20090323	Product data sheet	-	74AUP1G57 v.1
20061123	Product data sheet	-	-
	20150916 • Added type not 20120815 • Package outli 20111125 20100720 20090622 20090323	20150916 Product data sheet • Added type number 74AUP1G57GX (SOT1 20120815 Product data sheet • Package outline drawing of SOT886 (Figure 20111125 Product data sheet 20100720 Product data sheet 20090622 Product data sheet 20090323 Product data sheet	20150916 Product data sheet - • Added type number 74AUP1G57GX (SOT1255/X2SON6). 20120815 Product data sheet - • Package outline drawing of SOT886 (Figure 20) modified. 20111125 Product data sheet - 20100720 Product data sheet - 20090622 Product data sheet - 20090323 Product data sheet -

Low-power configurable multiple function gate

18. Legal information

18.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

18.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

18.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

74AUP1G57

All information provided in this document is subject to legal disclaimers.

Low-power configurable multiple function gate

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of

non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

18.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

19. Contact information

For more information, please visit: http://www.nexperia.com

For sales office addresses, please send an email to: salesaddresses@nexperia.com

74AUP1G57

Low-power configurable multiple function gate

20. Contents

Nexperia

1	General description 1
2	Features and benefits
3	Ordering information 2
4	Marking 2
5	Functional diagram 2
6	Pinning information
6.1	Pinning
6.2	Pin description
7	Functional description 4
7.1	Logic configurations 4
8	Limiting values 5
9	Recommended operating conditions 6
10	Static characteristics 6
11	Dynamic characteristics 9
12	Waveforms
13	Transfer characteristics
14	Waveform transfer characteristics 13
15	Package outline
16	Abbreviations
17	Revision history
18	Legal information
18.1	Data sheet status
18.2	Definitions
18.3	Disclaimers
18.4	Trademarks
19	Contact information
20	Contents 24

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Logic Gates category:

Click to view products by NXP manufacturer:

Other Similar products are found below:

5962-8769901BCA 74HC85N NL17SG08P5T5G NL17SG32DFT2G NLU1G32AMUTCG NLV7SZ58DFT2G NLVHC1G08DFT1G
NLVVHC1G14DTT1G NLX2G08DMUTCG NLX2G08MUTCG MC74HCT20ADR2G 091992B 091993X 093560G 634701C 634921A
NL17SG32P5T5G NL17SG86DFT2G NLU1G32CMUTCG NLV14001UBDR2G NLVVHC1G132DTT1G NLVVHC1G86DTT1G
NLX1G11AMUTCG NLX1G97MUTCG 746427X 74AUP1G17FW5-7 74LS38 74LVC1G08Z-7 74LVC32ADTR2G 74LVC1G125FW4-7
74LVC08ADTR2G MC74HCT20ADTR2G NLV14093BDTR2G NLV17SZ00DFT2G NLV17SZ02DFT2G NLV17SZ126DFT2G
NLV27WZ17DFT2G NLV74HC02ADR2G NLV74HC08ADR2G NLVVHC1GT32DFT1G 74HC32S14-13 74LS133 74LVC1G32Z-7
M38510/30402BDA 74LVC1G86Z-7 74LVC2G08RA3-7 M38510/06202BFA NLV74HC08ADTR2G NLV74HC14ADR2G
NLV74HC20ADR2G